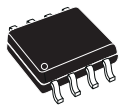
L9613B

DATA INTERFACE

- OPERATING POWER SUPPLY VOLTAGE RANGE 4.8V ≤ V_S ≤ 36V (40V FOR TRANSIENTS)
- REVERSE SUPPLY (BATTERY) PROTECTED DOWN TO V_S ≥ -24V
- STANDBY MODE WITH VERY LOW CURRENT CONSUMPTION IS_{SB} ≤ 1µA @ V_{CC} ≤ 0.5V
- MIN POSSIBLE BAUD RATE ACCORDING TO ISO9141 ≥ 130KBAUD
- TTL COMPATIBLE TX INPUT
- BIDIRECTIONAL K-I/O PIN WITH SUPPLY VOLTAGE DEPENDENT INPUT THRESHOLD
- OVERTEMPERATURE SHUT DOWN FUNCTION SELECTIVE TO K-I/O PIN
- WIDE INPUT AND OUTPUT VOLTAGE RANGE -24V ≤ VK ≤ VS
- K OUTPUT CURRENT LIMITATION, TYP IK = 60mA
- DEFINED OFF OUTPUT STATUS IN UNDERVOLTAGE CONDITION AND VS OR GND INTERRUPTION
- CONTROLLED OUTPUT SLOPE FOR LOW EMI
- HIGH INPUT IMPEDANCE FOR OPEN VS OR GND CONNECTION



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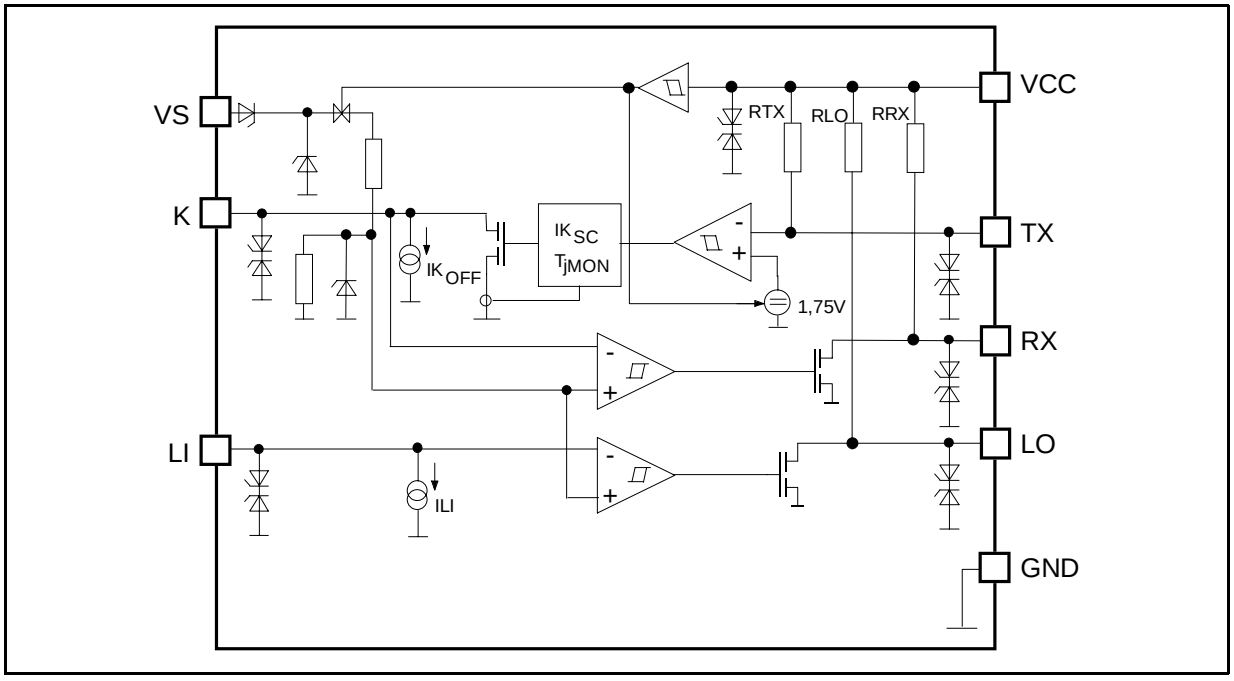
ORDERING NUMBERS: L9613B013TR (TAPE&REEL)
L9613B (TUBES)

- DEFINED OUTPUT ON STATUS OF LO OR RX FOR OPEN LI OR K INPUTS
- DEFINED K OUTPUT OFF FOR TX INPUT OPEN
- INTEGRATED PULL UP RESISTORS FOR TX, RX AND LO
- EMI ROBUSTNESS OPTIMIZED

DESCRIPTION

The L9613B is a monolithic integrated circuit containing medium speed data interface functions.

BLOCK DIAGRAM

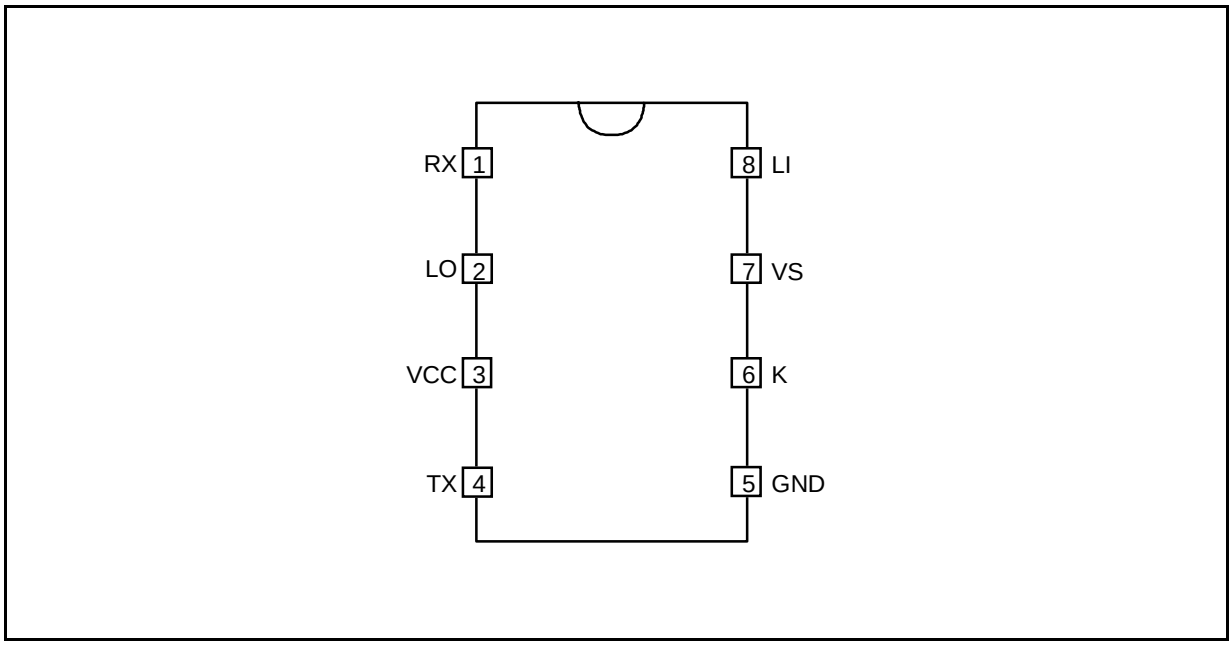


ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Value	Unit
V_S	Supply Voltage ISO transient t ≤ 400ms	-24 to +36 -24 to +40	V V
V_{CC}	Stabilized Voltage	-24V to 7	V
dV_S/dt	Supply Voltage Transient	-10 to +10	V/µs
$V_{LI,K}$	Pin voltage	-24 to V_S	V
$V_{LO, RX, TX}$	Pin voltage	-24 to V_{CC}	V

* max ESD voltages are +/-2KV with human body model C=100pF, R=1.5KΩ corresponds to maximum energy

PIN CONNECTION



THERMAL DATA

Symbol	Parameter	Min.	Typ.	Max.	Unit
T_{JSDon}	Temperature shutdown switch-on-threshold	160		200	°C
T_{JSDoff}	Temperature shutdown switch-off-threshold	150			°C
$R_{th(j-a)}$	Thermal steady state junction to ambient resistance	130	155	180	°C/W

PIN FUNCTIONS

N.	Name	Description
1	RX	Output for K as input
2	LO	Output L comparator
3	VCC	Stabilized voltage supply
4	TX	Input for K as output
5	GND	Common GND
6	K	Bidirectional I/O
7	VS	Supply voltage
8	LI	Input L comparator

ELECTRICAL CHARACTERISTICS (The electrical characteristics are valid within the below defined Operating Conditions, unless otherwise specified).

The function is guaranteed by design until T_{JSDon} temperature shutdown switch-on-threshold.

V_S Supply voltage 4.8 V... 18 V

V_{CC} Stabilized voltage 3 V... 7 V

T_J Junction temperature -40 °C... 150°C

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
I_{CC}	Supply V_{CC} Current	$V_{CC} \leq 5.5V$ VLI, VTX = 0V		1.4	2.5	mA
		$VK \geq VK_{high}$ $VLI \geq VLI_{high}$ $VTX = V_{CC}$ @ $V_{CC} \leq 5.5V$	-5	40	150	µA
IS_{ON}	Supply VS Current	VLI, VTX = 0V		3.5	10	mA
		$V_{CC} = 0.5V$ @ $V_S \leq 12V$ 3)		<1	50	µA
IS_{SB}		$V_{CC} = 0.5V$, see fig. 5 @ $V_S \leq 16V$			100	µA
VK_{low}	Input Voltage LOW State	RX output status LOW	-24		0.40VS	V
VK_{high}	Input Voltage HIGH State	RX output status HIGH	0.60VS		VS	V
VK_{hys}	Input Threshold Hysteresis	VK_{high} - VK_{low} $V_S \geq 8.0V$ $V_S \geq 6.0V$	 0.2 0.08	 0.05VS	 1.0	 V V
IK_{OFF}	Input Current	$VTX \geq VTX_{high}$ V_S, $V_{CC} \geq 0V$ or V_S, V_{CC} = open or GND = open	-5	4	40	µA
RK_{ON}	Output ON Impedance	@ $V_S \geq 6.5V$ $VTX \leq VTX_{low}$ $IK \geq 7mA$ 1)		10	30	Ω
IK_{SC}	Short Circuit Current	$V_S \geq 6.5V$	40	60	150	mA
VK_{sat}	Output Saturation Voltage	$R_{KO} = 1.5K\Omega$			1	V
VTX_{low}	Input Voltage LOW State		 -24		 1	 V
VTX_{high}	Input Voltage HIGH State		 3.5		 VCC	 V
RRX_{ON} RLO_{ON}	Output ON Impedance	$VK \leq VK_{low}$; $VLI \leq VLI_{low}$ $V_S \geq 6.5V$; $I_{RX,LO} \geq 1mA$		40	90	Ω
VRX_{sat} VLO_{sat}	Saturation Output Voltage	No external load			1	V
IRX_{SC} ILO_{SC}	Output short circuit current	$V_S \geq 6.5V$	 9	 20	 50	 mA
RTX	Input pull up resistance	Output status = (HIGH) $T_A \leq 85°C$ $-0.15V \leq VLO \leq VCC + 0.15V$ $-0.15V \leq VRX \leq VCC + 0.15V$	5	10	18	kΩ
RTX	Input pull up resistance	$-0.15V \leq VTX \leq VCC + 0.15V$ $T_{amb} \leq 125°C$	10	20	40	kΩ
VLI_{low}	Input voltage LOW state	LO output status LOW	-24		0.40VS	V
VLI_{high}	Input voltage HIGH state	LO output status HIGH	0.60VS		VS	V
ILI	Input current	VS, VCC ≥ 0V or VS, VCC = open or GND = open	-5	4	40	µA

Note 1) For external supplied output currents lower than this value a series protection diode can become active. See also Fig. 4 and 5.

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Unit
$C_{KI,LO,RX}$	Internal output capacities				20	pF
f_{LI-LO} f_{K-RX} f_{TX-K}	Transmission frequency	9V < V_S < 16V, (external loads) $T_{min} \geq 20 \cdot R_{KO} \cdot C_K - K_{line}$	130			kHz
f_{LI-LO} f_{K-RX} f_{TX-K}	Rise Time	for the definition of tr, tf see FIG. 1, 2)		0.4	2	µs
	Fall Time	9V < V_S < 16V, (external loads) $T_{min} \geq 20 \cdot R_{KO} \cdot C_K - K_{line}$		0.4	2	µs
$t_{OFF,LI-LO}$ $t_{OFF,K-RX}$ $t_{OFF,TX-K}$	Switch OFF time	for the definition of tr, tf see FIG. 1		1.3	3	µs
$t_{ON,LI-LO}$ $t_{ON,K-RX}$ $t_{ON,TX-K}$	Switch ON time	9V < V_S < 16V, (external loads) Tmin ≥ 20 · R_{KO} · C_K - K_{line}		1.3	3	µs
$td_{SB\ ON}$ $td_{SB\ OFF}$	Standby reaction time	VTX = 0V, IK ≥ 7mA VLI = 0V, 9V < VS < 16V see FIG. 2		10 20	20 40	µs µs

Note 2) Speed limitation related to external capacitance $C_{ext\ RX,\ LO}$ and internal impedance $C_{LO,\ RX}$, RLO, RRX for rise time.

$$t_r = R_{LO,\ RX} \cdot (C_{LO,RX} + C_{ext\ RX,\ LO}) \cdot 1.38.$$

Note 3) In case of spikes on VCC ≥ 0.5V KOUT will be switched On for typical 10µs which represents the standby td_{SB} reaction time.

FUNCTIONAL DESCRIPTION

The L9613B is a monolithic bus driver designed to provide bidirectional serial communication in automotive applications.

The device provides a bidirectional link, called K, to the V_{Bat} related diagnosis bus. It also includes a separate comparator L which is also able to be linked to the V_{Bat} bus. The input TX and output RX of K are related to VCC with her integrated pull up resistances. Also the L comparator output LO has a pull up resistance connected to VCC.

All VBat bus defined inputs LI and K have supply voltage dependent thresholds together with sufficent hysteresis to suppress line spikes. These pins are protected against overvoltages, shorts to GND and VS and can also be driven beyond VS and GND. These features are also given for TX, RX and LI only taking into account the behaviour of the internal pull up resistances. The thermal shut down function switches OFF the K output if the chip temperature increases above the thermal shut down threshold. To reactivate K again the chip temperature must decrease below the K switch ON temp. To achieve no fault for VS undervoltage conditions the outputs will be switched OFF and stay at high impedance. The device is also protected against reverse battery condition. During lack of VS or GND all pins shows high impedance characteristic. To realize a lack of the VS related bus line LI and K the outputs LO and RX shows defined ON status. Supressing all 4 classes of "Schaffner" signals (Schaffner 1; 2; 3a,b; 4) all pins can be load with short energy pulses of max. ±0.2mJ. All these features together with a high possible baud rate >130Kbaud, controlled output slopes for low EMI, a wide power supply voltage range and a real standby function with zero power consumption $IS_{SB\ typ} \leq 1\mu A$ during system depowering VCC ≤0.5V make this device high efficient for automotive bus system.

After wake up of the system from SB condition the first output signal will have an additional delay time $td_{typ} \leq 5\mu s$.

The typical output voltage behaviour for the K, LO, RX outputs as a function of the output current is shown in Fig.5. Fig.6 shows a waveform of the output signal when the low level changes from $R_{ON} \cdot I_{OUT}$ to $I_{OUT} \cdot 2 \cdot R_{ON} + U_{BE}$ state. This variation occurs due to too low output current or after a negative transient forced to the output or to the supply voltage line.

Figure 1. Input to output timings and output pulse shape

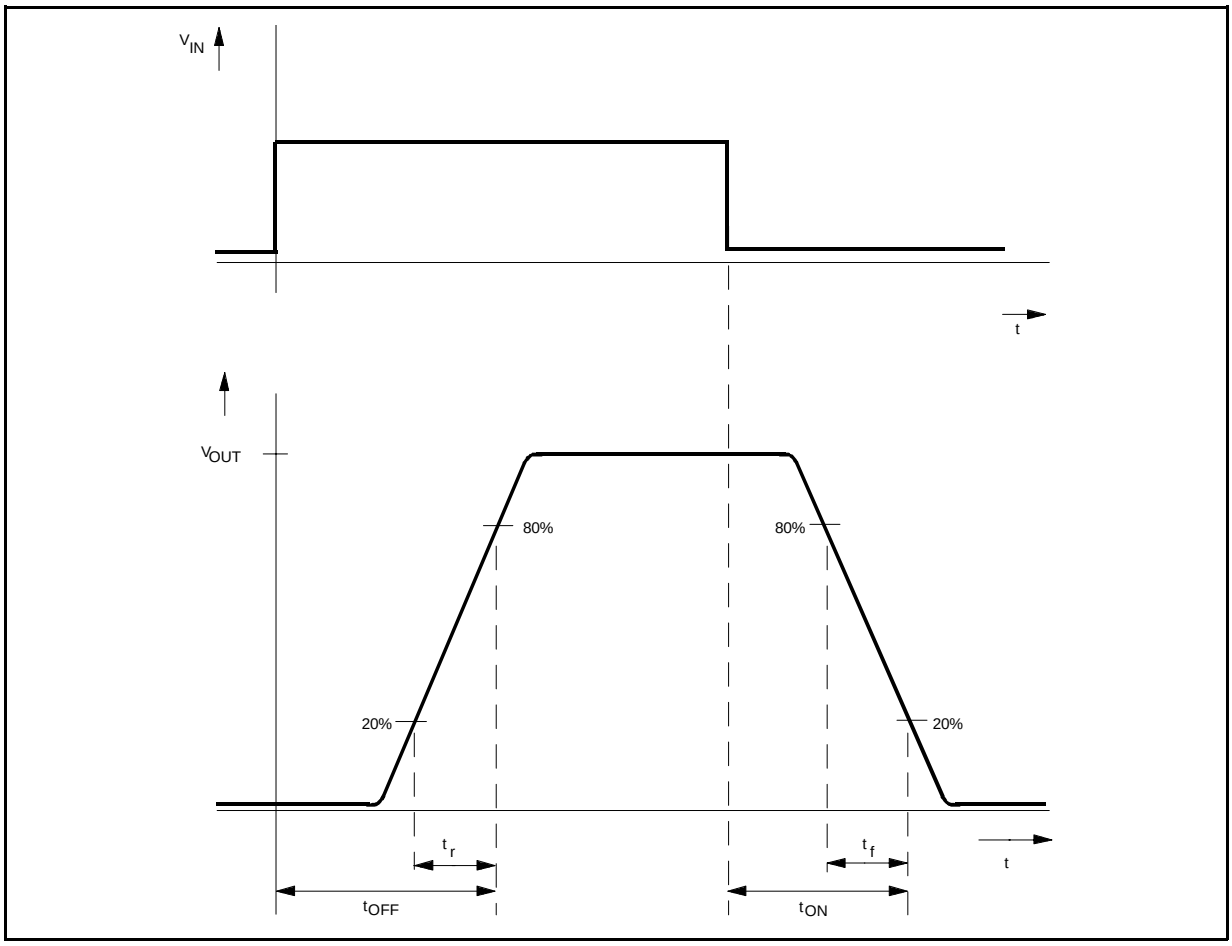


Figure 2. Standby reaction time.

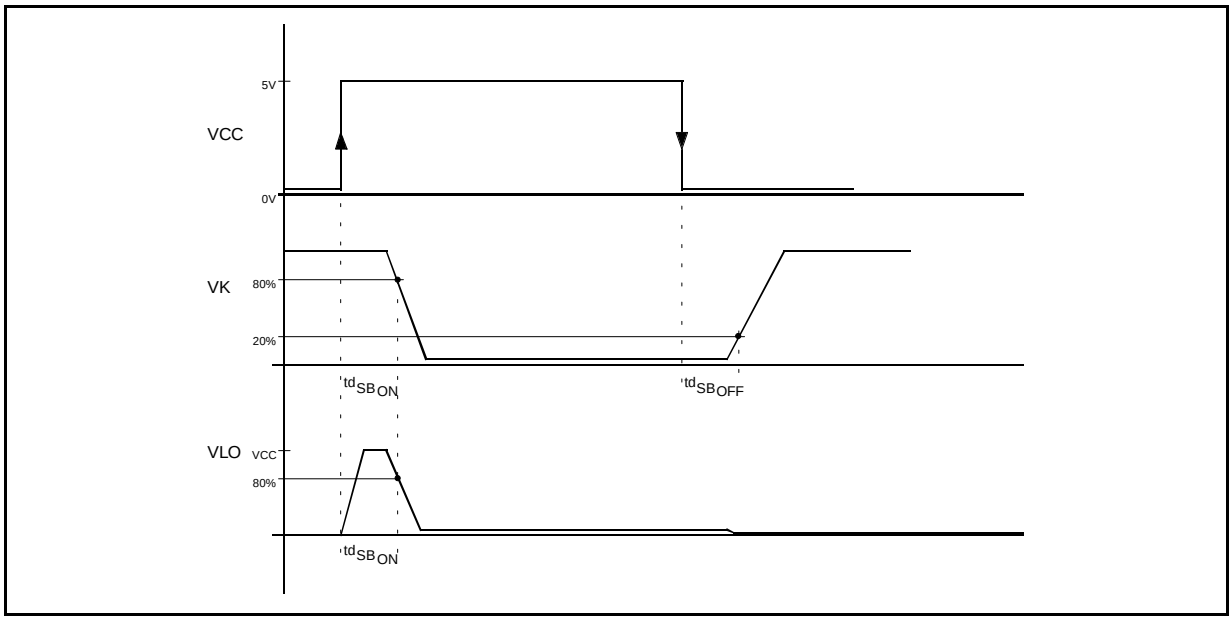


Figure 3. Output characteristics at K, LO, RX.

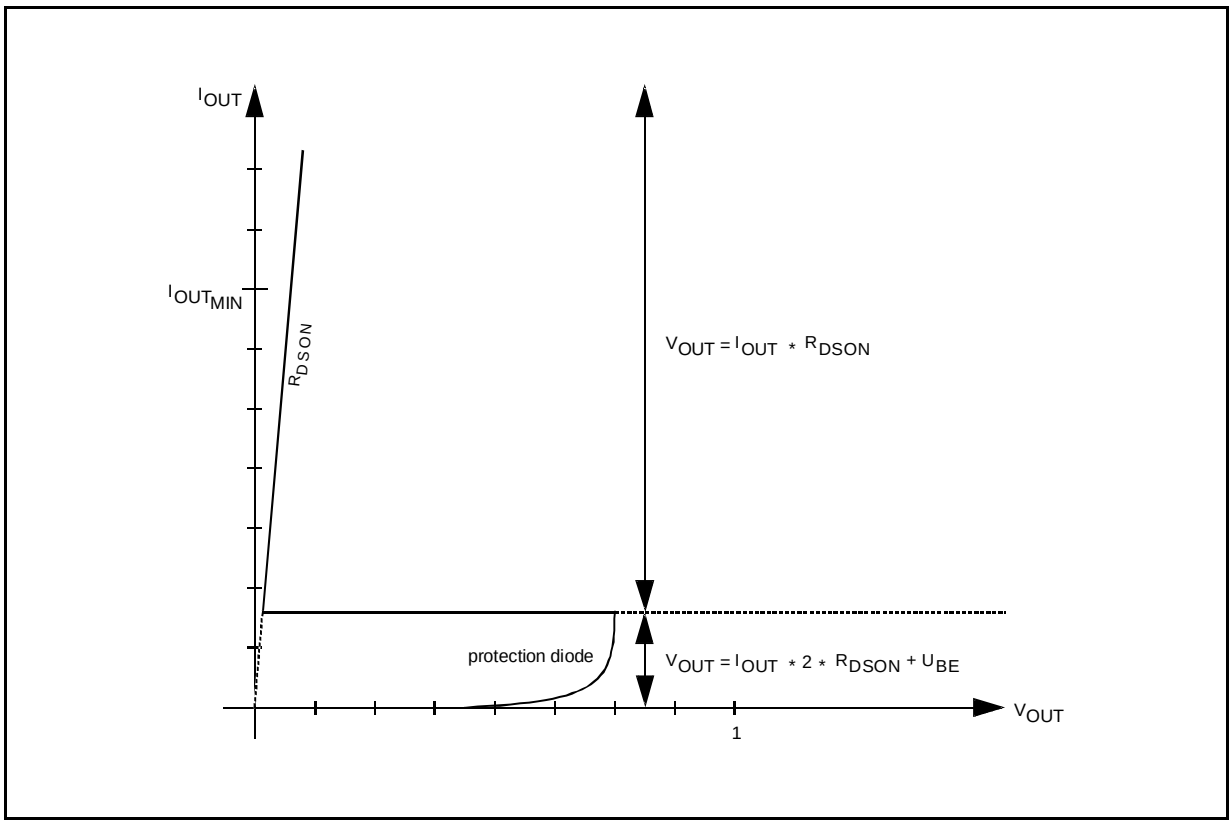


Figure 4. Output signal shape related to output current.

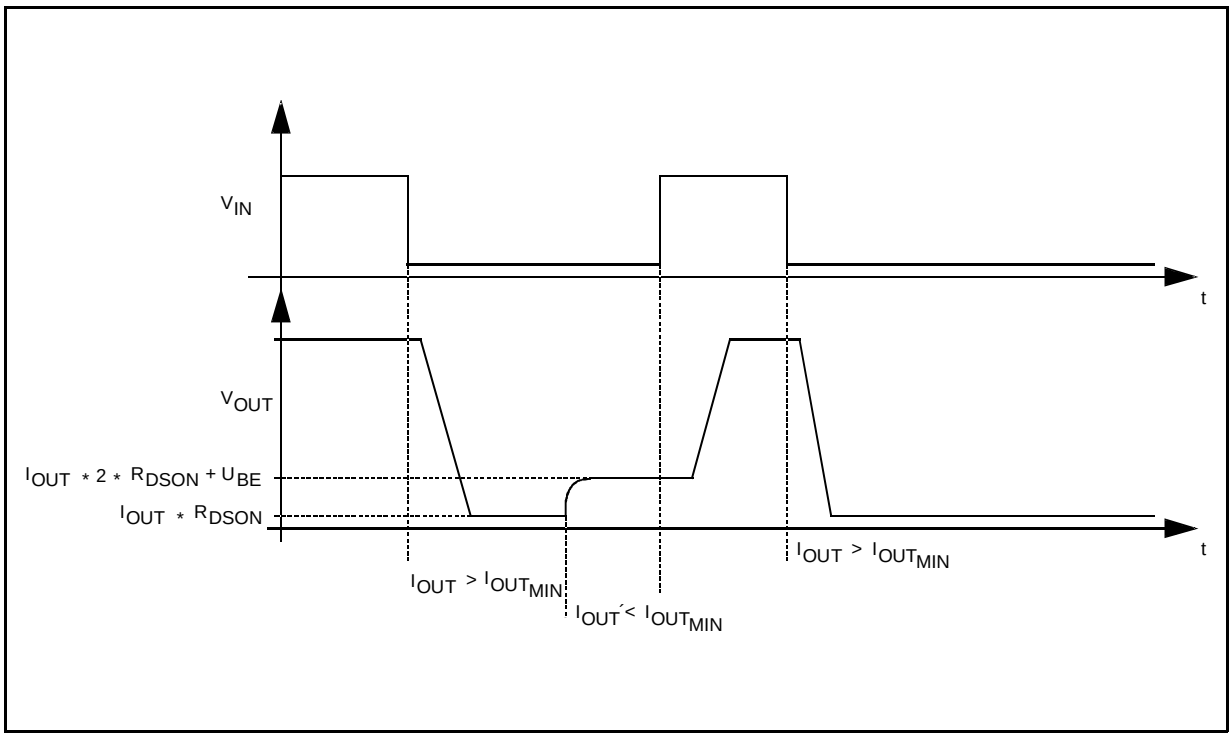


Figure 5. Standby current consumption.

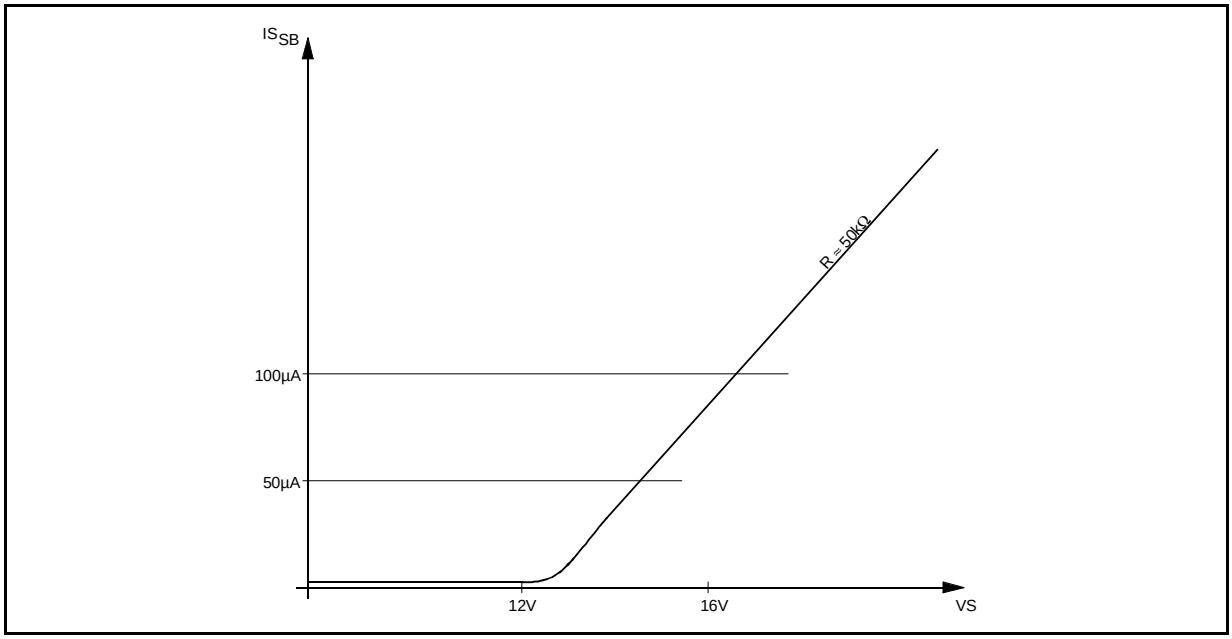
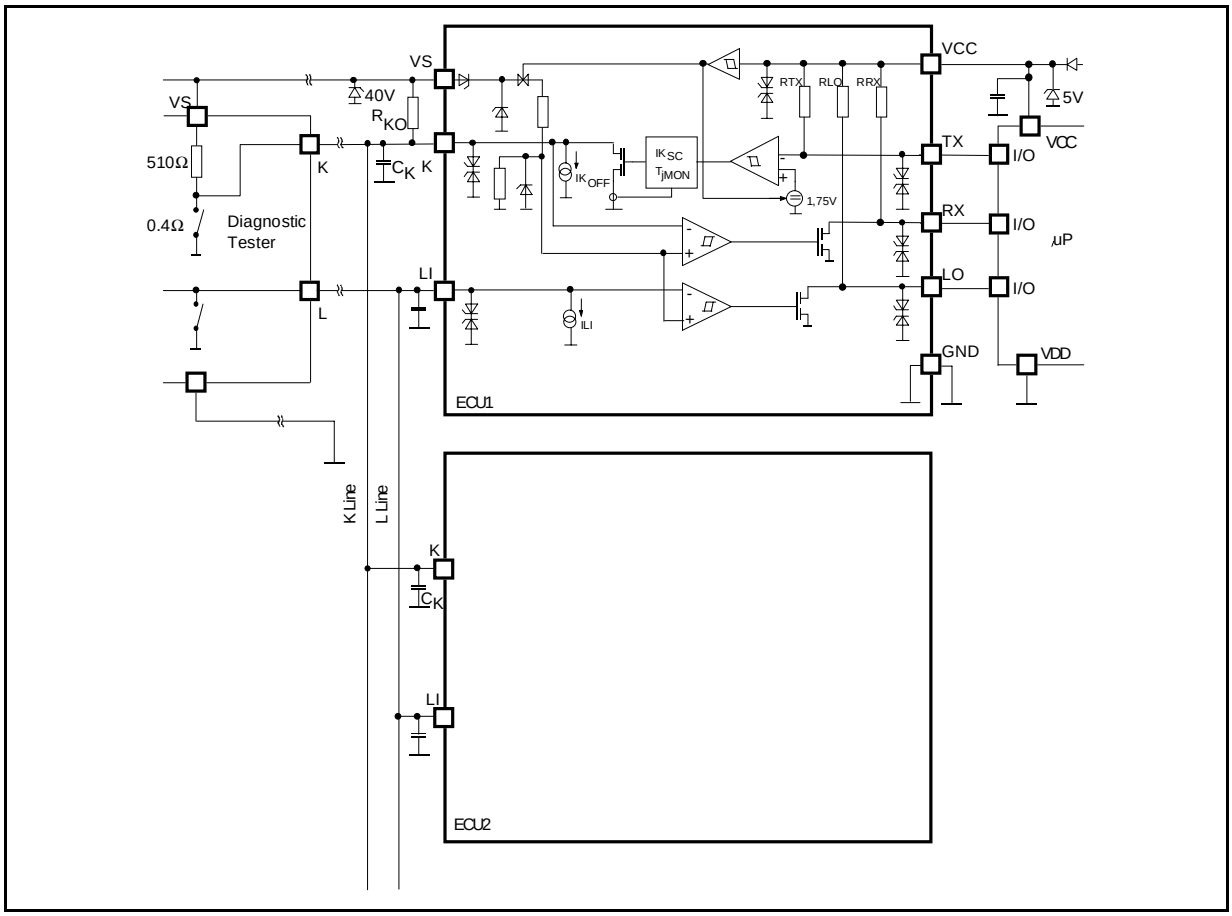


Figure 6. Application Circuit.



EMS Performance (ISO 9141 BUS system)

Figure 7.

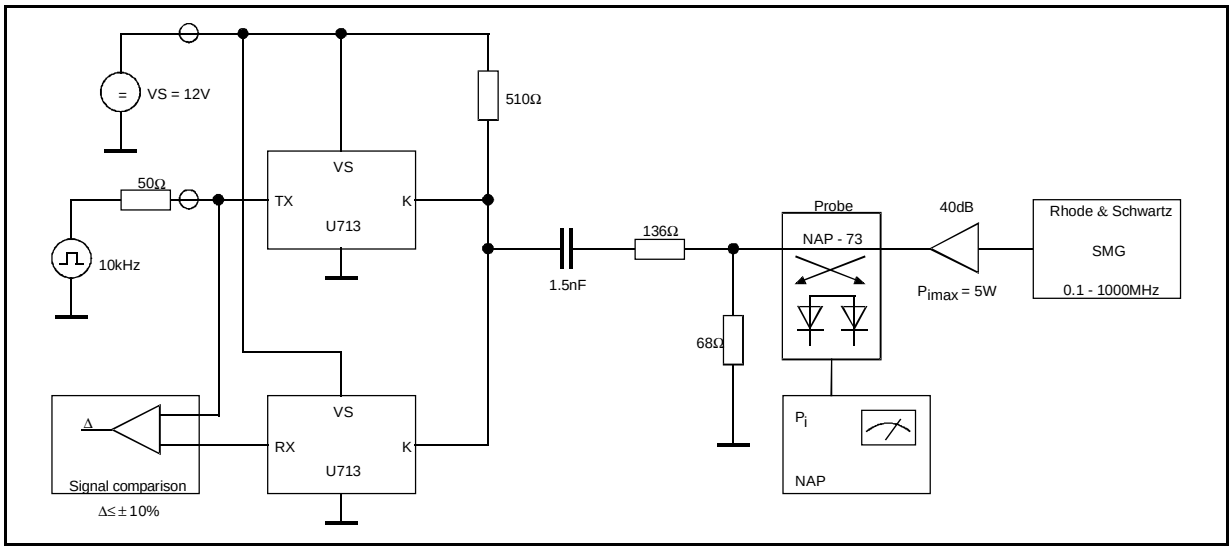
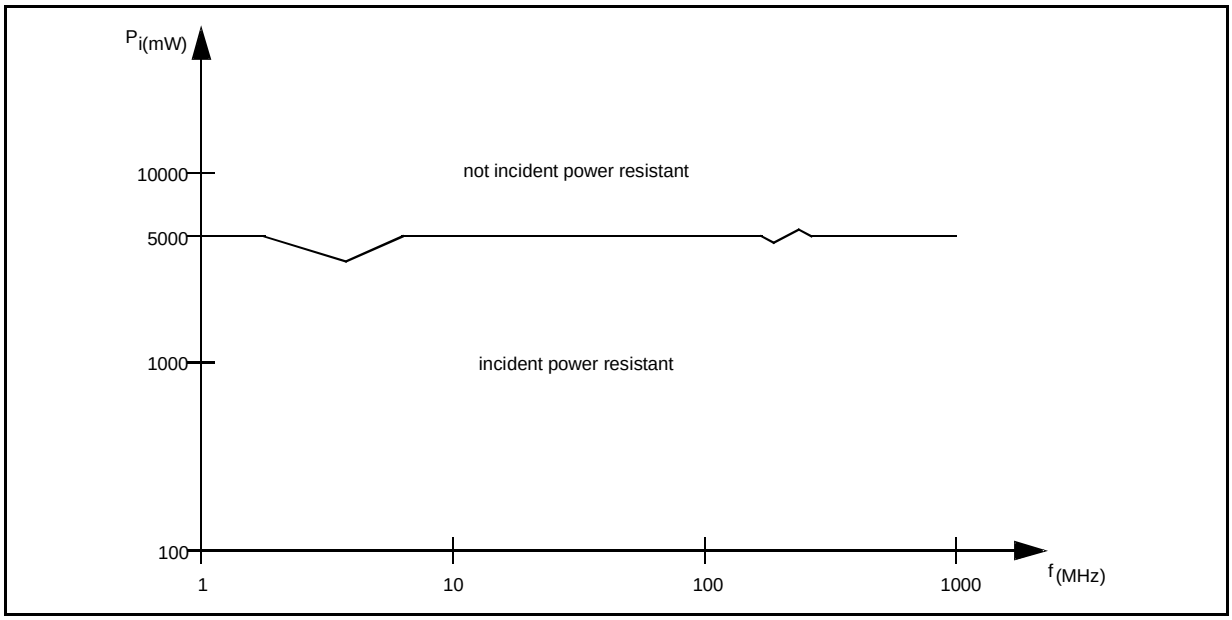


Figure 8.



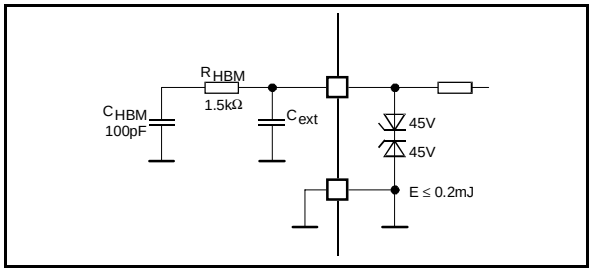
ESD application hints

To improve the ESD robustness of this device above specified ±2KV/HBM external blocking capacitors must be used. Nevertheless the max. energy which can be clamped by this device should not exceeds 0.2mJ for each pin. An equivalent input diagram for calculation can be seen in fig. 9.

ESD duscharge model

$$E_{ESD} = \frac{1}{2} C_{HBM} U_{ESD}^2 = 0.2mJ + \frac{1}{2} C_{EXT} \cdot (45V)^2$$

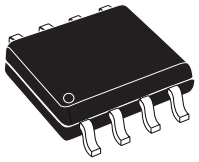
Figure 9.



DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
A			1.75			0.069
a1	0.1		0.25	0.004		0.010
a2			1.65			0.065
a3	0.65		0.85	0.026		0.033
b	0.35		0.48	0.014		0.019
b1	0.19		0.25	0.007		0.010
C	0.25		0.5	0.010		0.020
c1	45° (typ.)					
D (1)	4.8		5.0	0.189		0.197
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		3.81			0.150	
F (1)	3.8		4.0	0.15		0.157
L	0.4		1.27	0.016		0.050
M			0.6			0.024
S	8° (max.)					

(1) D and F do not include mold flash or protrusions. Mold flash or potrusions shall not exceed 0.15mm (.006inch).

OUTLINE AND MECHANICAL DATA



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